



ZVN2120G

200V N-CHANNEL ENHANCEMENT MODE VERTICAL MOSFET IN SOT223

Features and Benefits

- V_{(BR)DSS} > 200V
- R_{DS(ON)} ≤ 10 Ω @ V_{GS} = 10V
- Maximum Continuous Drain Current I_D = 0.32A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

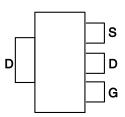
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (e3)
- Weight: 0.112 grams (Approximate)

Applications

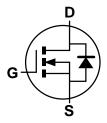
- DC-DC Converters
- Solenoids / Relay Driver for Automotive







Pin Out - Top



Equivalent Circuit

Ordering Information (Note 4)

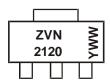
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN2120GTA	ZVN2120	7 8		1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT223



ZVN2120 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	200	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	I _D	0.32	A
Pulsed Drain Current	I _{DM}	2	Α
Power Dissipation	P _D	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

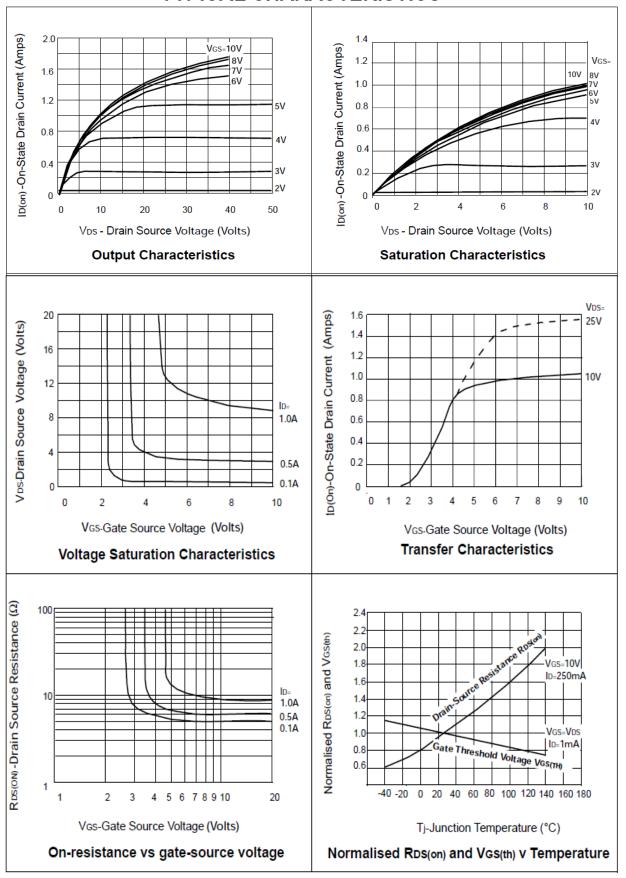
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	200	-	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	ı	-	10 100	μA μA	V _{DS} = 200V, V _{GS} = 0V V _{DS} = 160V, V _{GS} = 0V, T _J = +125°C (Note 7)	
Gate-Source Leakage	I _{GSS}	-	-	±20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
On-State Drain Current (Note 6)	I _{D(ON)}	500	-	-	mA	$V_{GS} = 10V, V_{DS} = 25V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Static Drain-Source On-Resistance (Note 6)	R _{DS(ON)}	-	-	10	Ω	$V_{GS} = 10V, I_D = 250mA$	
Forward Transconductance (Notes 6 & 7)		100	-	-	mS	$V_{DS} = 25V, I_D = 250mA$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C _{iss}	-	-	85	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	-	-	20	pF		
Reverse Transfer Capacitance	C _{rss}	-	-	7	pF		
Turn-On Delay Time (Note 8)	t _{D(ON)}	-	-	8	ns	V _{DD} = 25V, I _D = 250mA	
Turn-On Rise Time (Note 8)	t _R	-	-	8	ns		
Turn-Off Delay Time (Note 8)	t _{D(OFF)}	-	-	20	ns		
Turn-Off Fall Time (Note 8)	t _F	-	-	12	ns		

Notes:

- 5. Short duration pulse test used to minimize self-heating effect.
- 6. Measured under pulsed conditions. Width=300ms. Duty cycle \leq 2%.
- 7. Guaranteed by design. Not subject to product testing.
 8. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.

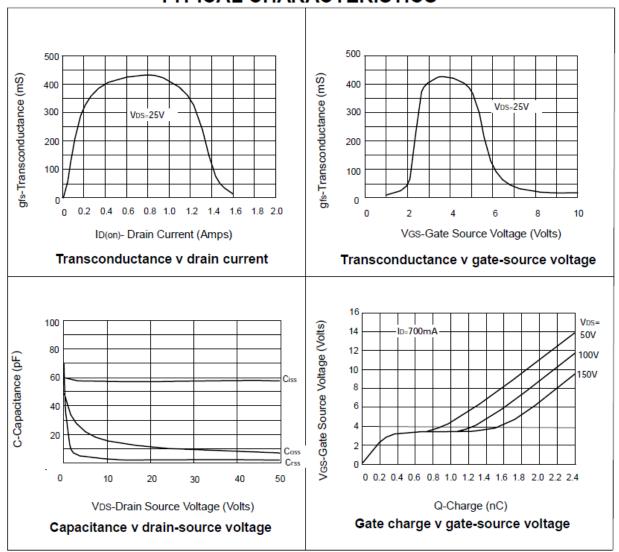


TYPICAL CHARACTERISTICS





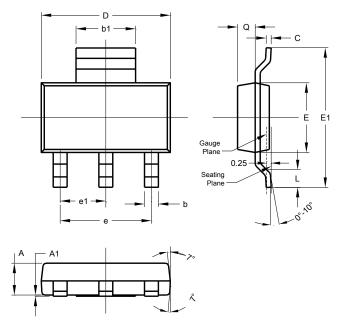
TYPICAL CHARACTERISTICS





Package Outline Dimensions

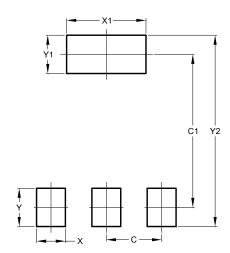
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
C	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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